

Features

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and a Ubi ZUWfjb[
`dfcWgg
- High packing density
- PÜPÁÜj&{ } ÁV!æ}••c{!

Descriptions

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Characteristic	Symbol	Rating	Unit
Output voltage	V _O	50	V
Input voltage	V _I	15,-5	V
Output current	I _O	100	mA
Power dissipation	P _D	200	mW
Junction temperature	T _J	150	°C
Storage temperature range	T _{stg}	-55 ~ 150	°C

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Output cut-off current	I _{O(OFF)}	V _O =50V, V _I =0	-	-	500	nA

